## NSN 5961-00-421-2993

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Inclosure Material:
Metal all transistor
Overall Length:
0.170 inches all transistor and 0.210 inches all transistor
Terminal Length:
0.500 inches all transistor
Overall Diameter:
0.209 inches all transistor and 0.230 inches all transistor
Internal Configuration:
Field effect all transistor
Component Function Relationship:
Matched
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal all transistor
Terminal Circle Diameter:
0.100 inches all transistor
Features Provided:
Burn in and hermetically sealed case
Semiconductor Material:
Silicon all transistor
Power Rating Per Characteristic:
300.0 milliwatts total device dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction all transistor
Special Features:
Each transistor is unitized
Precious Material And Location:
Terminals gold
Precious Material:
Gold
Terminal Type And Quantity:
6 uninsulated wire lead all transistor
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
Fiig. A110a0
Arroad